



# LED Display Product Data Sheet LTD-5250HR-03J

Spec No.: DS30-2006-110

Effective Date: 09/20/2006

Revision: -

**LITE-ON DCC**

**RELEASE**

BNS-OD-FC001/A4

**FEATURES**

- \* 0.52INCH (13.2mm) DIGIT HEIGHT
- \* CONTINUOUS UNIFORM SEGMENTS
- \* LOW POWER REQUIREMENT
- \* EXCELLENT CHARACTERS APPEARANCE
- \* HIGH BRIGHTNESS & HIGH CONTRAST
- \* WIDE VIEWING ANGLE
- \* SOLID STATE RELIABILITY
- \* CATEGORIZED FOR LUMINOUS INTENSITY
- \* **LEAD-FREE PACKAGE (ACCORDING TO ROHS)**

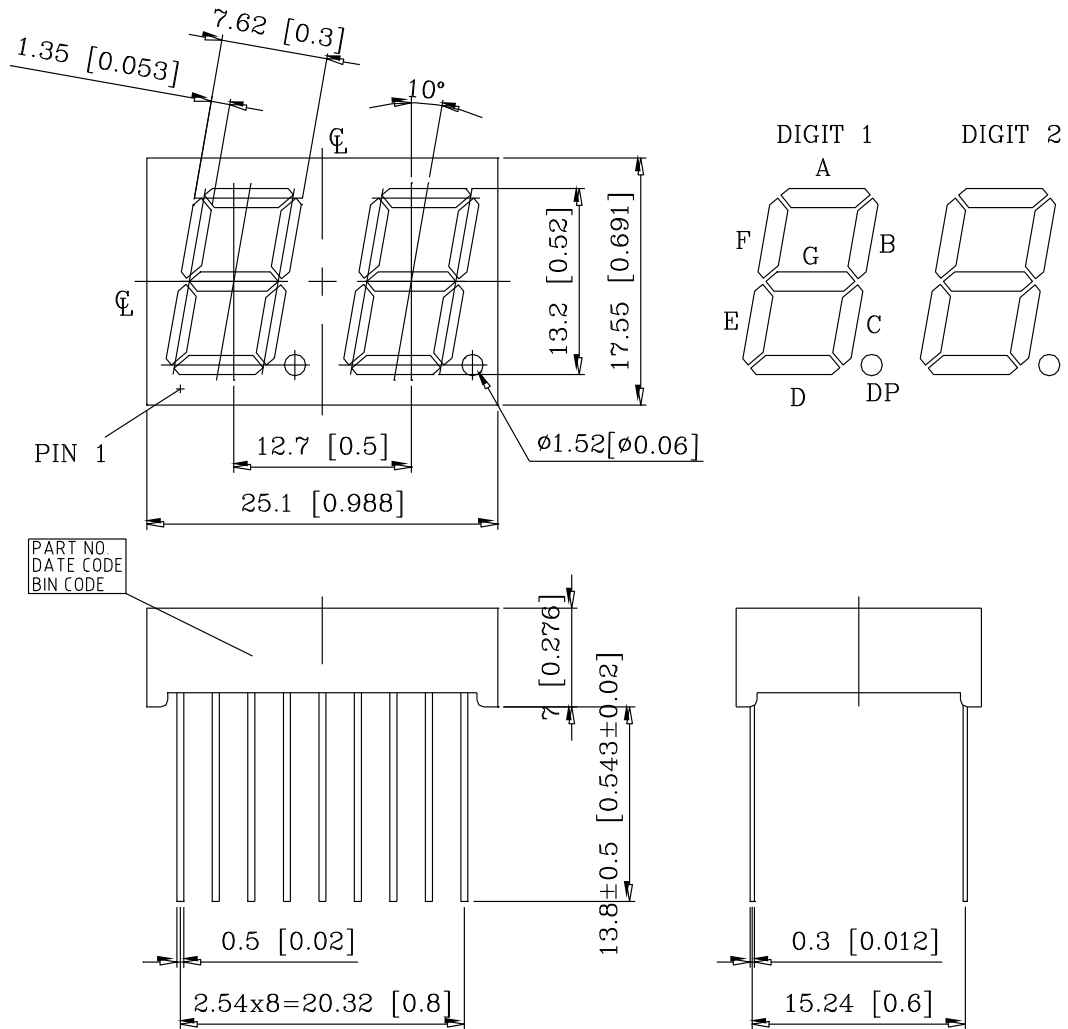
**DESCRIPTION**

The LTD-5250HR-03J is a 0.52inch (13.2mm) digit height dual digit seven-segment display. The device utilizes Hi-Eff. Red LED chips, which are made from GaAsP on a transparent GaP substrate, and has a black face and red segments.

**DEVICE**

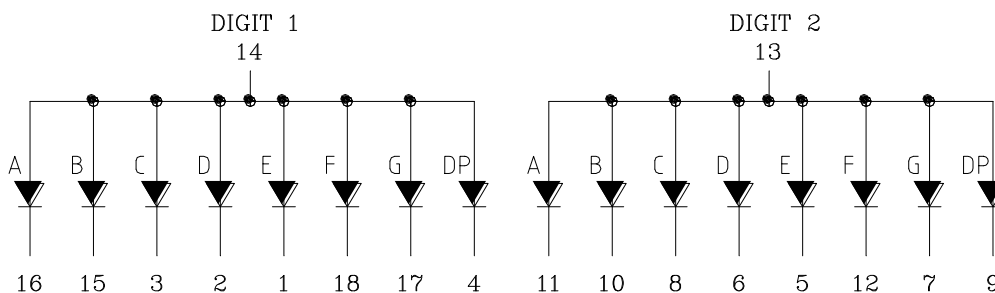
PART NO.	DESCRIPTION
HI-EFF. RED	COMMON ANODE
LTD-5250HR-03J	RT. HAND DECIMAL

## PACKAGE DIMENSIONS



- NOTES: 1. All dimensions are in millimeters. Tolerances are  $\pm 0.25$  mm unless otherwise note.  
 2. Pin tip's shift tolerance is  $\pm 0.4$  mm.

## INTERNAL CIRCUIT DIAGRAM



Property of Lite-On Only

**PIN CONNECTION**

<b>No.</b>	<b>CONNECTION</b>
1	CATHODE E (DIGIT 1)
2	CATHODE D (DIGIT 1)
3	CATHODE C (DIGIT 1)
4	CATHODE DP (DIGIT 1)
5	CATHODE E (DIGIT 2)
6	CATHODE D (DIGIT 2)
7	CATHODE G (DIGIT 2)
8	CATHODE C (DIGIT 2)
9	CATHODE DP (DIGIT 2)
10	CATHODE B (DIGIT 2)
11	CATHODE A (DIGIT 2)
12	CATHODE F (DIGIT 2)
13	COMMON ANODE (DIGIT 2)
14	COMMON ANODE (DIGIT 1)
15	CATHODE B (DIGIT 1)
16	CATHODE A (DIGIT 1)
17	CATHODE G (DIGIT 1)
18	CATHODE F (DIGIT 1)

**ABSOLUTE MAXIMUM RATING AT T<sub>A</sub>=25°C**

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation Per Chip	75	mW
Peak Forward Current Per Chip ( 1/10 Duty Cycle, 0.1ms Pulse Width )	100	mA
Continuous Forward Current Per Chip	25	mA
Derating Linear From 25°C Per Chip	0.33	mA/°C
Reverse Voltage Per Chip	5	V
Operating Temperature Range	-35°C to +105°C	
Storage Temperature Range	-35°C to +105°C	

Soldering Conditions: 1/16 inch below seating plane for 3 seconds at 260<sup>0</sup>C  
or of temperature unit (during assembly) not over max. temperature rating above.

**TRICAL / OPTICAL CHARACTERISTICS AT T<sub>A</sub>=25°C**

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I <sub>v</sub>	800	2200		μcd	I <sub>F</sub> =10mA
Peak Emission Wavelength	λ <sub>p</sub>		635		nm	I <sub>F</sub> =20mA
Spectral Line Half-Width	Δλ		40		nm	I <sub>F</sub> =20mA
Dominant Wavelength	λ <sub>d</sub>		623		nm	I <sub>F</sub> =20mA
Forward Voltage Per Chip	V <sub>F</sub>		2.0	2.6	V	I <sub>F</sub> =20mA
Reverse Current Per Chip	I <sub>R</sub>			100	μA	V <sub>R</sub> =5V
Luminous Intensity Matching Ratio (Similar Light Area)	I <sub>v-m</sub>			2:1		I <sub>F</sub> =10mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.

## TYPICAL ELECTRICAL / OPTICAL CHARACTERISTIC CURVES

(25°C Ambient Temperature Unless Otherwise)

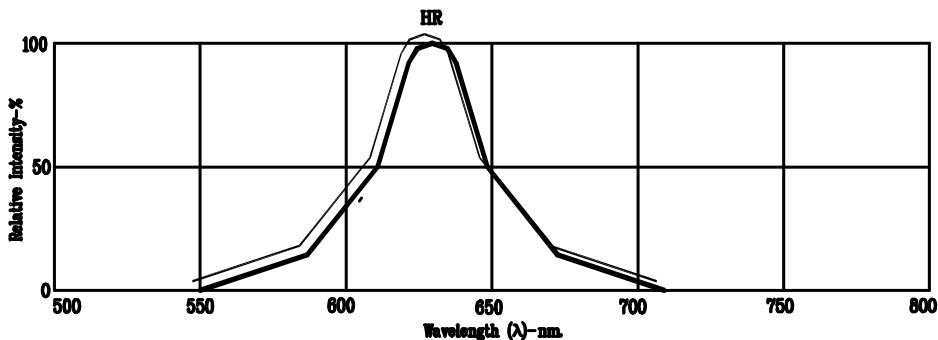


Fig.1. RELATIVE INTENSITY VS. WAVELENGTH

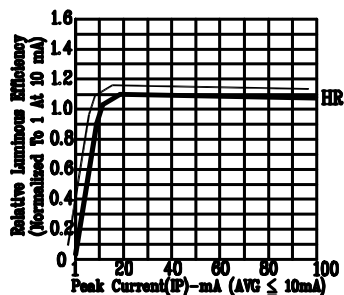


Fig.2. RELATIVE LUMINOUS EFFICIENCY (LUMINOUS INTENSITY PER UNIT CURRENT) VS. PEAK CURRENT (REFRESH RATE 1KHz)

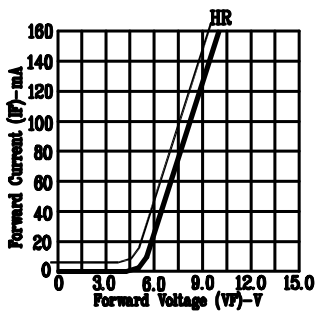


Fig.3. FORWARD CURRENT VS. FORWARD VOLTAGE

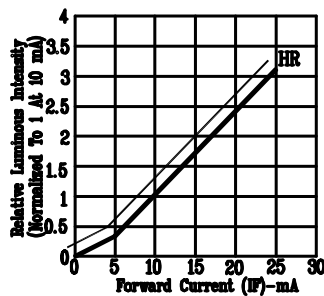


Fig.4. RELATIVE LUMINOUS INTENSITY VS. FORWARD CURRENT

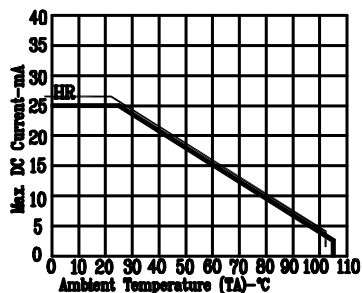


Fig.5. MAX. ALLOWABLE DC CURRENT VS. AMBIENT TEMPERATURE.

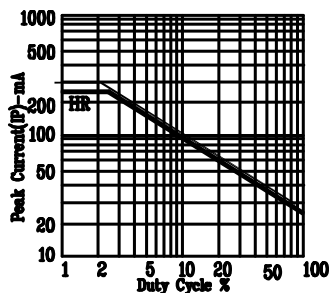


Fig.6. MAX. PEAK CURRENT VS. DUTY CYCLE % (REFRESH RATE 1KHz)

FORM: HD-UT - FEB 08/09